EPISTAR

ES-SAHRPN10D

AlGaInP PN-series LED Chip

> Mechanical Specification:

- (1) Dimension
 - Chip size: 10 mil x 10 mil (235±25 μm x 235±25 μm)
 - Thickness: 6.7 mil (170±25 μm)
 - N bonding pad: 3.7 mil (95±10 $\mu m)$
- (2) Metallization
 - Topside N electrode: Au alloy
 - Backside P electrode: Au alloy

Features:

- \cdot High luminous intensity
- · Thin film structure
- · Vertical electrode
- · High driving current

Applications:

- · Outdoor display
- Traffic signal
- Automotive
- · Consumer electronic

> Electro-optical Characteristics at 25°C:

Parameter	Symbol		Condition	Min.	Тур.	Max.	Unit
Forward Voltage	Vf1		lf = 10μΑ	1.3	-	-	V
	Vf2		lf = 20mA	-	2.1	2.5	V
Reverse Current	lr		Vr = 10V	-	-	5.0	μΑ
Peak Wavelength	λρ		lf = 20mA	-	631	-	nm
Dominant Wavelength ⁽¹⁾	λd		lf = 20mA	619	624	629	nm
Spectra Half-width	Δλ		lf = 20mA	-	20	-	nm
Luminous Intensity ⁽²⁾⁽³⁾	lv	E18	If = 20mA	600	-	-	mcd
		E19		650	-	-	
		E20		700	-	-	
		E21		770	-	-	

electrode

Si-substrate

P-electrode

Note:

(1) Basically, the wavelength span is 10nm; however, customers' special requirements are also welcome.

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(3) Luminous intensity is measured by EPISTAR's equipment on bare chips.

> Absolute Maximum Ratings:

Parameter	Symbol	Condition	Rating	Unit
Forward DC Current	lf	Ta = 25°C	≤ 50	mA
Reverse Voltage	Vr	Ta = 25°C	≤ 10	V
Junction Temperature	Tj	-	≤ 115	°C
		Chip	-40 ~ +85	°C
Storage Temperature	Tstg	Chip-on-tape/storage	5 ~ 35	°C
		Chip-on-tape/transportation	-20 ~ +65	°C
Temperature during Packaging	-	-	280(<10sec)	°C

Note: Maximum ratings are package dependent. The above maximum ratings were determined using a Printed Circuit Board (PCB) without an encapsulant. Stresses in excess of the absolute maximum ratings such as forward current and junction temperature may cause damage to the LED.

> Characteristic Curves:

Fig.1 - Relative luminous Intensity vs. Forward Current

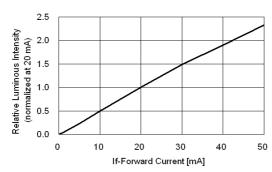


Fig.3 – Relative Intensity (@20mA) vs. Ambient Temperature

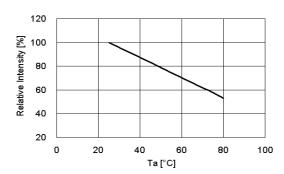


Fig.5 – Dominant Wavelength (@20mA) vs. Ambient Temperature

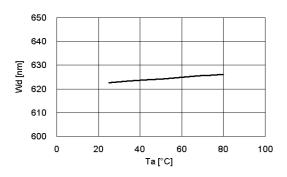


Fig.2 – Forward Current vs. Forward Voltage

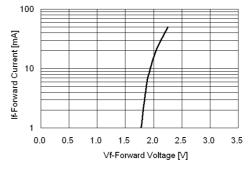


Fig.4 – Forward Voltage (@20mA) vs. Ambient Temperature

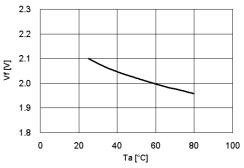


Fig.6 – Maximum Driving Forward DC Current vs. Ambient Temperature (De-rating based on Tj max. = 115°C)

